

# isc N-Channel MOSFET Transistor

# IRFZ44Z, IIRFZ44Z

# • FEATURES

- Static drain-source on-resistance: R<sub>DS</sub>(on) ≤13.9mΩ
- · Enhancement mode
- · Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

# DESCRITION

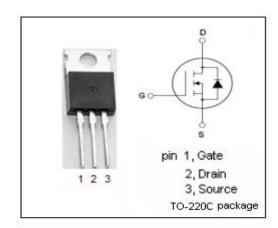
• reliable device for use in a wide variety of applications

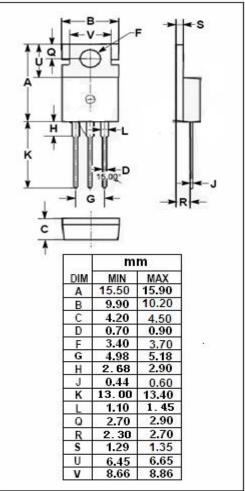
# • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	55	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	51	А
I <sub>DM</sub>	Drain Current-Single Pulsed	200	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	80	W
Tj	Max. Operating Junction Temperature	175	${\mathbb C}$
T <sub>stg</sub>	Storage Temperature	-55~175	°C

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	1.87	°C/W
Rth(ch-a)	Rth(ch-a) Channel-to-ambient thermal resistance		°C/W







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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 250 μ A	55			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =250 μ A	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =31A			13.9	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±20V			±0.2	μ <b>А</b>
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =55V; V <sub>GS</sub> = 0V			20	μ <b>A</b>
V <sub>SD</sub>	Diode forward voltage	Is =31A, V <sub>GS</sub> = 0 V			1.2	V

#### **NOTICE:**

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